

## **Product Selector Guide**

SiC FETS, SiC JFETs and SiC Schottky Diodes

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Q1 - 2021

# United SiC

#### High Performance SiC FETs , JFETs and Schottky Diodes

#### **Key Features**

- Multiple V<sub>DS</sub> options: 650/750/900/1200/1700V
- Lowest RDS(on)
  - 7mΩ @ 650V
  - 9mΩ @ 1200V
- Gen 4 SiC FETs (UJ4C Series)
  - 750V,  $18m\Omega$  and  $60m\Omega$  options
  - Best-in-class RDS(on) x Area delivers lowest conduction losses
  - Improves the  $Q_{\rm rr}$  and  $E_{\rm on}/E_{\rm off}$  losses at a given RDS(on)
  - Reduces both  $C_{oss(er)}/E_{oss}$  and  $C_{oss(tr)}$
- High performance cascode configuration
- Excellent body diode (Vf < 2V)
- Drive with any Si and/or SiC gate drive voltage
- Superior thermal performance
- Integrated ESD and gate protection
- Industry standard packages, including Kelvin source
- Majority of devices are AEC-Q101 qualified

#### **End Applications**

- Electric Vehicles
- Battery Chargers
- Telecom and Server PSU
- Circuit Protection
- Solar Inverters
- Energy Storage
- Motor drives













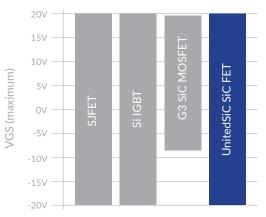




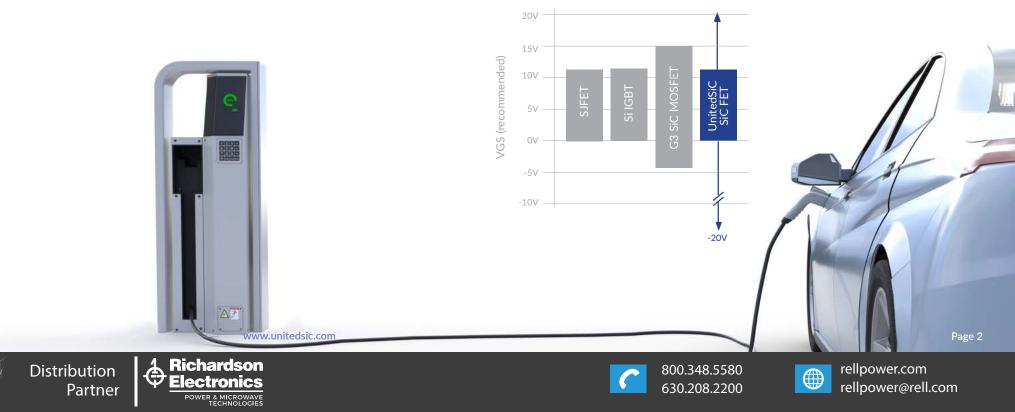
### Flexible Design Without Changing Gate Drive Voltage

- Replaces Si IGBTs, Si FETs, SiC MOSFETs or
- Si Superjunction devices
- SiC FET design guidelines available to support successful upgrade
- Innovative cascode configuration enables Si and SiC gate voltage compatibility
- Integrated clamping diode protects gates from |20V| with built-in ESD protection

#### Superior Gate and ESD Protection



#### 12V/0V Operation Simplifies Upgrading





#### SiC FETs UF3C/UF3SC/UJ3C/UJ4C Series Selector Guide

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Volt.	RDS(on) mΩ 25°C	RDS(on) mΩ 125°C	Generation	TO-247-3L	TO-247-4L	D2PAK-3L	TO-220-3L	D2PAK-7L	DFN 8X8
650V	6.7	8.8	Gen 3 Fast		UF3SC065007K4S				
	27	35 -	Gen 3 Fast	UF3C065030K3S <sup>(1)</sup>	UF3C065030K4S	UF3C065030B3 <sup>(1)</sup>	UF3C065030T3S <sup>(1)</sup>	UF3SC065030B7S	
			Gen 3 General Purpose	UJ3C065030K3S		UJ3C065030B3	UJ3C065030T3S		
	34	48	Gen 3 Fast						UF3SC065030D8S
	42	59	Gen 3 Fast	UF3C065040K3S	UF3C065040K4S	UF3C065040B3	UF3C065040T3S	UF3SC065040B7S	
	45	67	Gen 3 Fast						UF3SC065040D8S
	80	111	Gen 3 Fast	UF3C065080K3S <sup>(1)</sup>	UF3C065080K4S	UF3C065080B3 <sup>(1)</sup>	UF3C065080T3S <sup>(1)</sup>	UF3C065080B7S	
			Gen 3 General Purpose	UJ3C065080K3S		UJ3C065080B3	UJ3C065080T3S		
750V	18	31	Gen 4	UJ4C075018K3S	UJ4C075018K4S				
	56	106	Gen 4	UJ4C075060K3S	UJ4C075060K4S				
1200V	8.6	13.5	Gen 3 Fast		UF3SC120009K4S				
	16	25	Gen 3 Fast	UF3SC120016K3S	UF3SC120016K4S				
	35	56	Gen 3 Fast	UF3C120040K3S	UF3C120040K4S			UF3SC120040B7S	
			Gen 3 General Purpose	UJ3C120040K3S					
	70	111	Gen 3 General Purpose	UJ3C120070K3S					
	80	132	Gen 3 Fast	UF3C120080K3S	UF3C120080K4S			UF3C120080B7S	
			Gen 3 General Purpose	UJ3C120080K3S					
	150	254 -	Gen 3 Fast		UF3C120150K4S			UF3C120150B7S	
			Gen 3 General Purpose	UJ3C120150K3S					
	410	775	Gen 3 Fast	UF3C120400K3S					
1700V	410	775	Gen 3 Fast	UF3C170400K3S					

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Notes:

(1)  $\,$  Q(rr) for UF3C FAST device lower than equivalent UJ3C device  $\,$ 

All data represents current information as of March, 2021.

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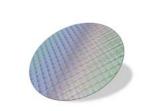


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### SiC JFETs UJ3N/UF3N Series Selector Guide





Voltage	Rdson (mΩ)	Idmax (A) at 25°C	Generation	Wafer (Contact Sales)	TO-247-3L
4700) (	1100	3.9	Gen 3	UJ3N1701K2	
1700V	400	8*	Gen 3	UF3N170400	
	140	20*	Gen 3	UF3N120140	
	70	33.5	Gen 3	UJ3N120070	UJ3N120070K3S
1200V	66	34	Gen 3		UJ3N120065K3S
	35	63	Gen 3	UJ3N120035	UJ3N120035K3S
	735	4*	Gen 3	UF3N090800	
900V	330	8*	Gen 3	UF3N090350	
	580	4*	Gen 3	UF3N065600	
	265	8*	Gen 3	UF3N065300	
650V	80	32	Gen 3	UJ3N065080	UJ3N065080K3S
	25	85	Gen 3	UJ3N065025	UJ3N065025K3S

\*Note(s):

1) \*Limited by bondwire.

2) Advanced information for wafer parts, please refer to product datasheet for specifications.



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<b>SiC Schottky</b> UJ3D Series Sel					and the second sec	
Voltage	Current Rating	Generation	TO-220-2L	TO-247-3L	TO-247-2L	
1700V	25A	Gen 3			UJ3D1725K2	
	2A	Gen 3	UJ3D1202TS			
	5A	Gen 3	UJ3D1205TS			
	2 x 5A	Gen 3		UJ3D1210KSD		
1200V	10A	Gen 3	UJ3D1210TS	UJ3D1210KS	UJ3D1210K2	
	2 x 10A	Gen 3		UJ3D1220KSD		
	20A	Gen 3			UJ3D1220K2	
	50A	Gen 3		UJ3D1250K	UJ3D1250K2	
	4A	Gen 3	UJ3D06504TS			
	6A	Gen 3	UJ3D06506TS			
	8A	Gen 3	UJ3D06508TS			
	10A	Gen 3	UJ3D06510TS			
(50)(	12A	Gen 3	UJ3D06512TS			
650V	16A	Gen 3	UJ3D06516TS			
	2 x 10A	Gen 3		UJ3D06520KSD		
	20A	Gen 3	UJ3D06520TS			
	30A	Gen 3	UJ3D06530TS			
	2 x 30A	Gen 3		UJ3D06560KSD		

Note(s):

1) For all die inquiries, contact sales@unitedsic.com

2) All data represents current information as of March, 2021.















# **FETJet**<sup>™</sup> CALCULATOR

## Start Designing Now - Make quick and confident datadriven design decisions

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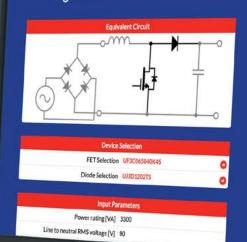
- Instantly select optimal SiC device
- Delivers loss and thermal estimates



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## Single Phase Power Factor Corrector, Continuous to Boundary Conduction Mode



Parameters
36.7
51.9
51.9
0.32
0.0579
nd Temperature

Conduction [W]	28.4
Turn-on switching [W]	7.5
Turn-off switching [W]	4.8
Total [W]	40.7
FET junction temperature [°C]	123

Losses per Diode and Temperature

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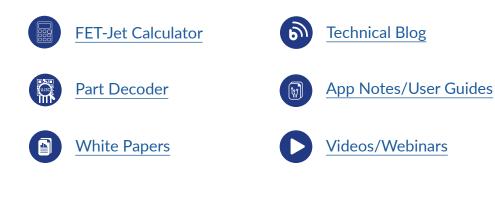
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Get Started Now - UnitedSiC provides extensive resources to help get your new design on the right track



Additional technical content supporting the move to higher performance SiC power designs can be found <u>HERE</u>





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